



# 10ppm/°C, 1μA, 1.25V SHUNT VOLTAGE REFERENCE

## FEATURES

- MICRO-PACKAGE: SOT23-3
- WIDE CURRENT RANGE: 1μA to 5mA
- HIGH INITIAL ACCURACY: 0.2%
- EXCELLENT SPECIFIED DRIFT PERFORMANCE:
  - 30ppm/°C (max) from 0°C to +70°C
  - 50ppm/°C (max) from -40°C to +85°C

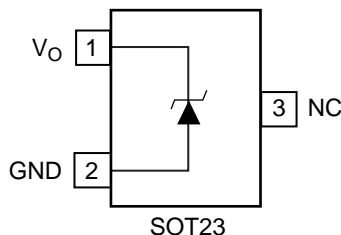
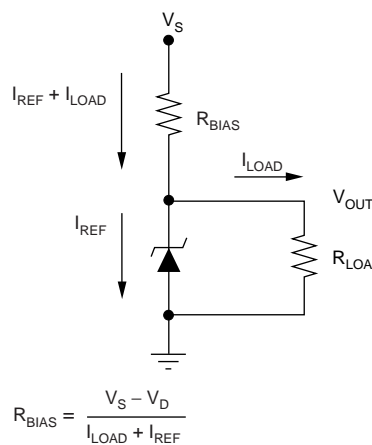
## APPLICATIONS

- BATTERY-POWERED INSTRUMENTS
- PORTABLE DEVICES
- MEDICAL EQUIPMENT
- CURRENT SOURCES
- CALIBRATORS
- MICROPOWER CURRENT AND VOLTAGE REFERENCE

## DESCRIPTION

The REF1112 is a two-terminal shunt reference designed for power- and space-sensitive applications. The REF1112 features an operating current of 1mA in a SOT23-3 package and is an improved, lower power solution for designs currently using voltage references in larger packages, such as the REF1004 and LT1004. The REF1112 is specified from -40°C to +85°C with operation extending from -40°C to +125°C.

The REF1112 complements other 1μA components from Texas Instruments including the OPA349 and the TLV240x low-power operational amplifiers, and the TLV349x micropower voltage comparator.



NC indicates pin should be left unconnected.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

All trademarks are the property of their respective owners.

## ABSOLUTE MAXIMUM RATINGS<sup>(1)</sup>

Reverse Breakdown Current .....	10mA
Forward Current .....	10mA
Operating Temperature .....	-55°C to +125°C
Storage Temperature .....	-65°C to +150°C
Junction Temperature .....	+150°C

(1) Stresses above these ratings may cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those specified is not implied.



## ELECTROSTATIC DISCHARGE SENSITIVITY

Electrostatic discharge can cause damage ranging from performance degradation to complete device failure. Texas Instruments recommends that all integrated circuits be handled and stored using appropriate ESD protection methods.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet published specifications.

## PACKAGE/ORDERING INFORMATION<sup>(1)</sup>

PRODUCT	PACKAGE-LEAD	PACKAGE DESIGNATOR	SPECIFIED TEMPERATURE RANGE	PACKAGE MARKING	ORDERING NUMBER	TRANSPORT MEDIA, QUANTITY
REF1112	SOT23-3	DBZ	-40°C to +125°C	R11A	REF1112AIDBZT	Tape and Reel, 250
"	"	"	"	"	REF1112AIDBZR	Tape and Reel, 3000

NOTE: (1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at [www.ti.com](http://www.ti.com).

## ELECTRICAL CHARACTERISTICS

**Boldface** limits apply over the specified temperature range,  $T_A = -40^\circ\text{C}$  to  $+125^\circ\text{C}$ .

At  $T_A = +25^\circ\text{C}$ ,  $I_{REF} = 1.2\mu\text{A}$  and  $C_{LOAD} = 10\text{nF}$ , unless otherwise noted.

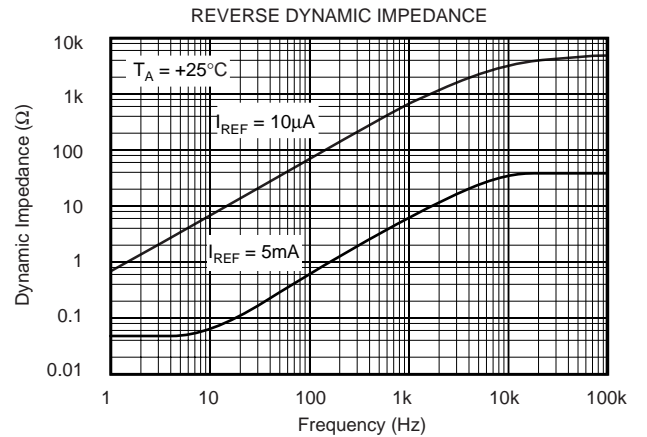
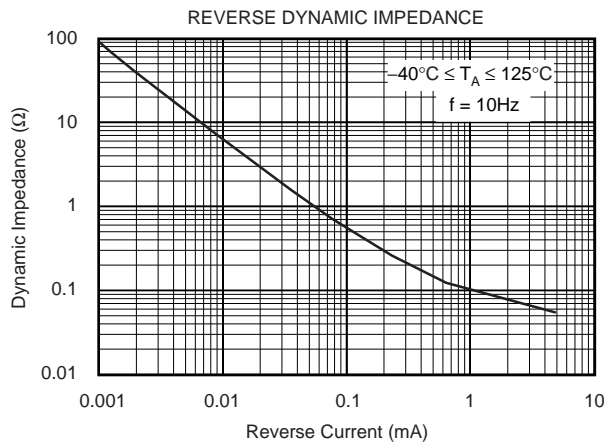
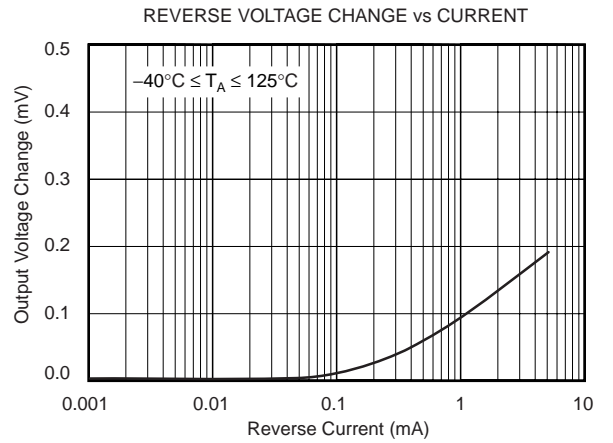
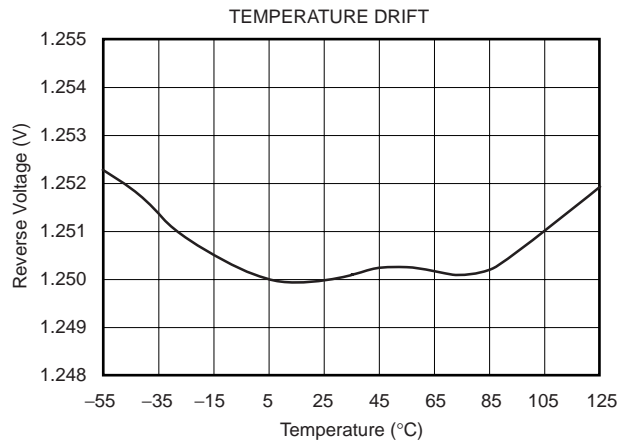
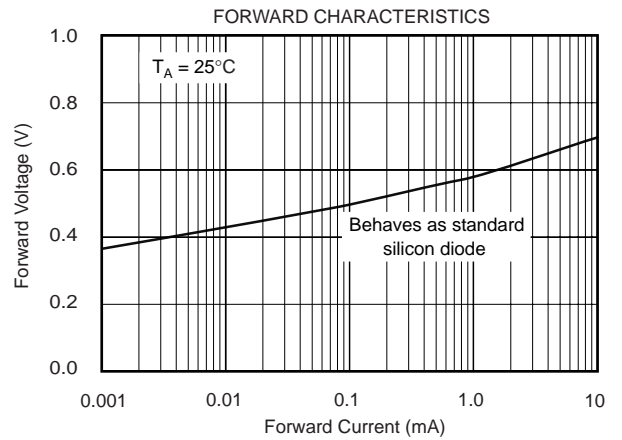
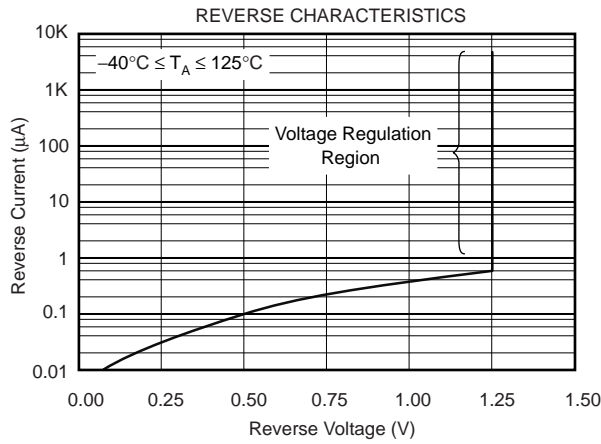
PARAMETER	CONDITIONS	REF1112 - 1.25V			UNITS
		MIN	TYP	MAX	
REVERSE BREAKDOWN VOLTAGE	$I_{REF} = 1.2\mu\text{A}$	1.2475 -0.2	1.25	1.2525 +0.2	V %
TEMPERATURE COEFFICIENT	$1.2\mu\text{A} \leq I_{REF} \leq 5\text{mA}$ , $0^\circ\text{C}$ to $+70^\circ\text{C}$ $1.5\mu\text{A} \leq I_{REF} \leq 5\text{mA}$ , $-40^\circ\text{C}$ to $+85^\circ\text{C}$ $1.5\mu\text{A} \leq I_{REF} \leq 5\text{mA}$ , $-40^\circ\text{C}$ to $+125^\circ\text{C}$		<b>10</b> <b>15</b> <b>15</b>	<b>30</b> <b>50</b>	ppm/°C ppm/°C ppm/°C
MINIMUM OPERATING CURRENT			1	1.2	$\mu\text{A}$
REVERSE BREAKDOWN VOLTAGE CHANGE WITH CURRENT	$1.2\mu\text{A} \leq I_{REF} \leq 5\text{mA}$		30	100	ppm/mA
REVERSE DYNAMIC IMPEDANCE	$1.2\mu\text{A} \leq I_{REF} \leq 5\text{mA}$		0.037	0.125	$\Omega$
LOW-FREQUENCY NOISE <sup>(1)</sup> 0.1Hz $\leq I_{REF} \leq 10\text{Hz}$			25		$\mu\text{V}_{PP}$
THERMAL HYSTERESIS <sup>(2)</sup>			100		ppm
LONG-TERM STABILITY $+25^\circ\text{C} \pm 0.1^\circ\text{C}$			60		ppm/kHr
TEMPERATURE CHARACTERISTICS					
Specified Range		-40		+125	°C
Operating Range		-40		+125	°C
Storage Range		-40		+150	°C
Thermal Resistance SOT23-3 Surface-Mount	$\theta_{JA}$		135		°C/W

(1) Peak-to-peak noise is measured with a 2-pole high-pass filter at 0.1Hz and a 4-pole, low-pass Chebyshev filter at 10Hz.

(2) Thermal hysteresis is defined as the change in output voltage after operating the device at  $+25^\circ\text{C}$ , cycling the device through the specified temperature range, and returning to  $+25^\circ\text{C}$ .

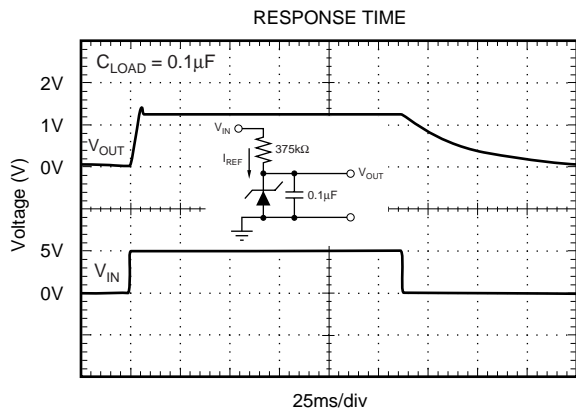
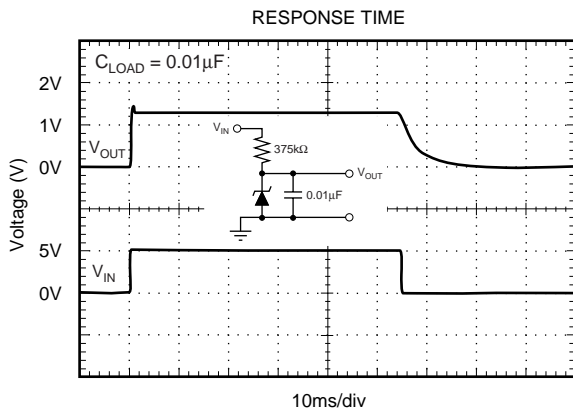
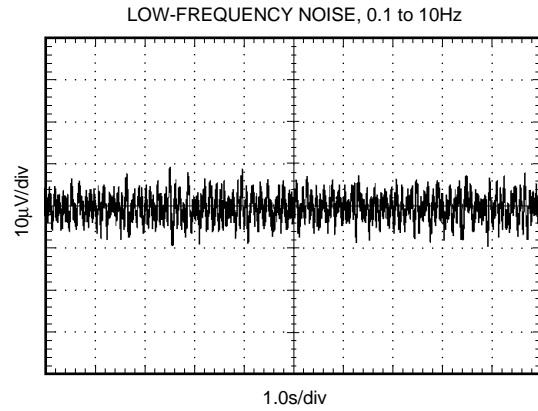
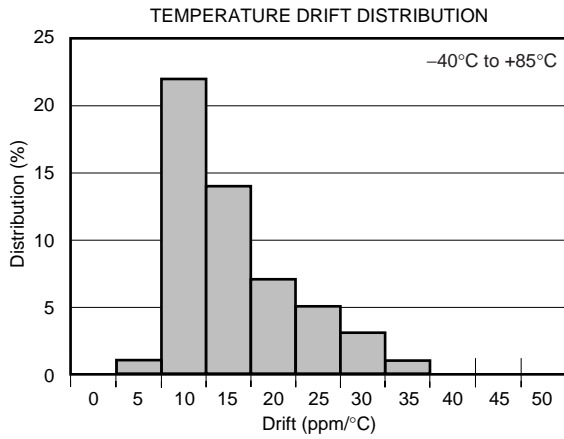
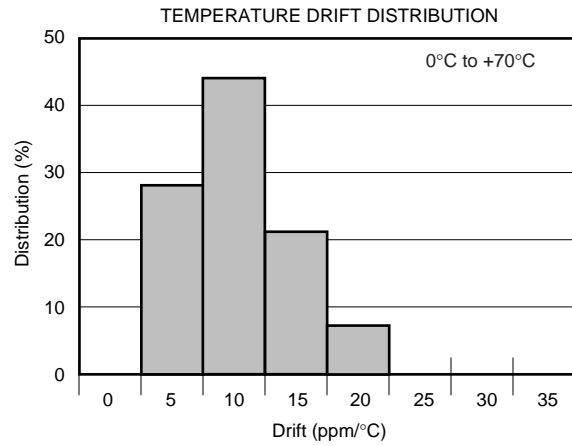
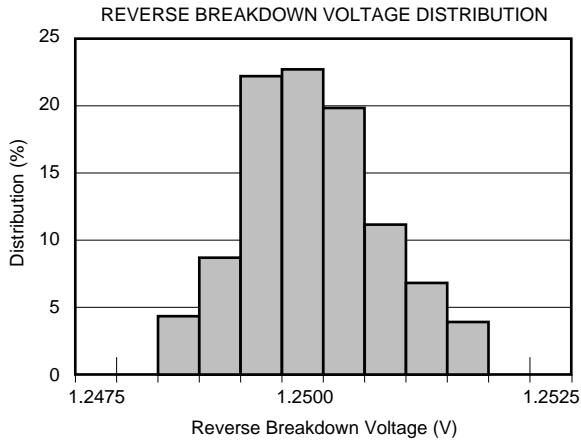
# TYPICAL CHARACTERISTICS

At  $T_A = +25^\circ\text{C}$ ,  $I_{REF} = 10\mu\text{A}$  and  $C_{LOAD} = 10\text{nF}$ , unless otherwise noted.



# TYPICAL CHARACTERISTICS (Continued)

At  $T_A = +25^\circ\text{C}$ ,  $I_{REF} = 10\mu\text{A}$  and  $C_{LOAD} = 10\text{nF}$ , unless otherwise noted.



# APPLICATIONS INFORMATION

The REF1112 is a two-terminal bandgap reference diode designed for high accuracy with outstanding temperature characteristics at low operating currents. Precision thin-film resistors result in 0.2% initial voltage accuracy and 50ppm/°C maximum temperature drift. The REF1112 is specified from -40°C to +85°C, with operation from -40°C to +125°C, and is offered in a SOT23-3 package.

Typical connections for the REF1112 are shown in Figure 1. A minimum 1µA bias current is required to maintain a stable output voltage and can be provided with a resistor connected to the supply voltage.  $I_{BIAS}$  depends on the values selected for  $R_{BIAS}$  and  $V_S$ , and will vary as a sum of the minimum operating current and the load current. To maintain stable operation, the value of  $R_{BIAS}$  must be low enough to maintain the minimum operating current at the minimum and maximum load and supply voltage levels.

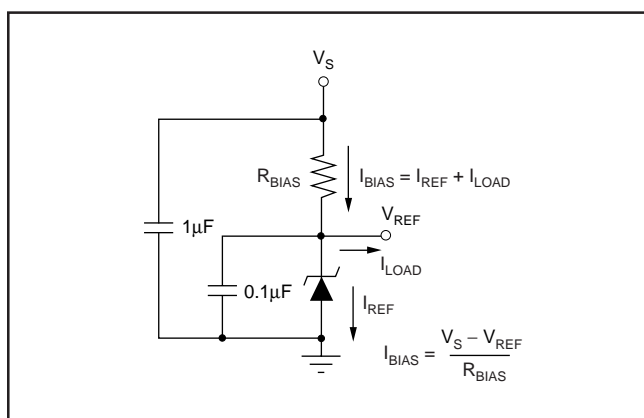


FIGURE 1. Typical Connections.

A 0.1µF load capacitor is recommended to maintain stability under varying load conditions. A minimum 0.01µF load capacitor is required for stable operation. Start-up time for the REF1112 will be affected, depending on the value of load capacitance and the bias currents being used. A 1µF power-supply bypass capacitor is recommended to minimize supply noise within the circuit.

The REF1112 shunt voltage reference provides a versatile function for low power and space-conservative applications. The REF1112 can be configured with an additional diode and NPN transistor to provide a temperature compensated current reference as shown in Figure 2. The REF1112 can be scaled to provide extremely low power reference voltages. Figure 3 shows the REF1112 used as a 1V out, 3µA voltage reference, and in Figure 4 as a 2.5V reference on 1µA.

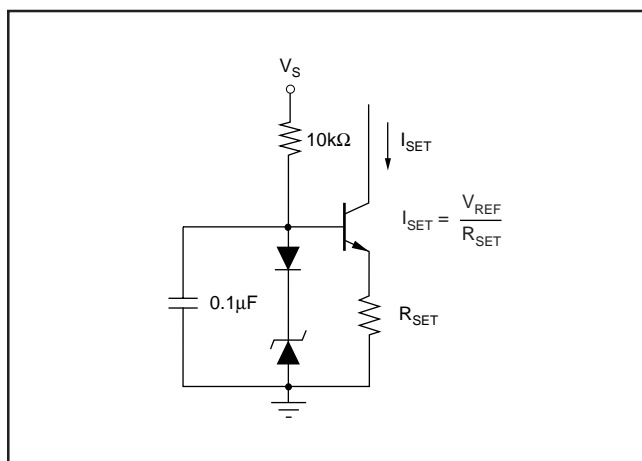


FIGURE 2. REF1112 Provides a Stable Current Source.

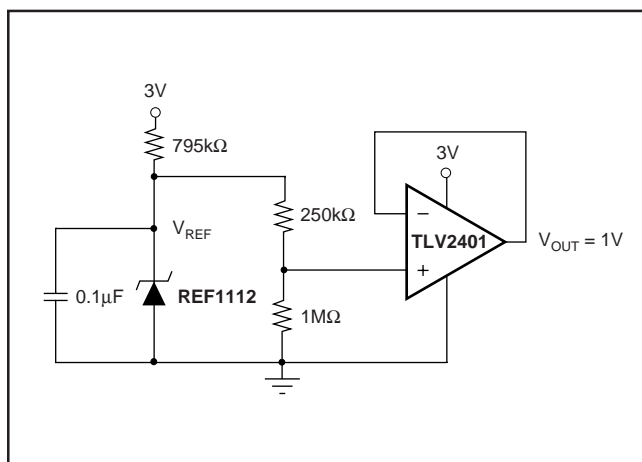


FIGURE 3. MicroPOWER 3µA 1V Voltage Reference.

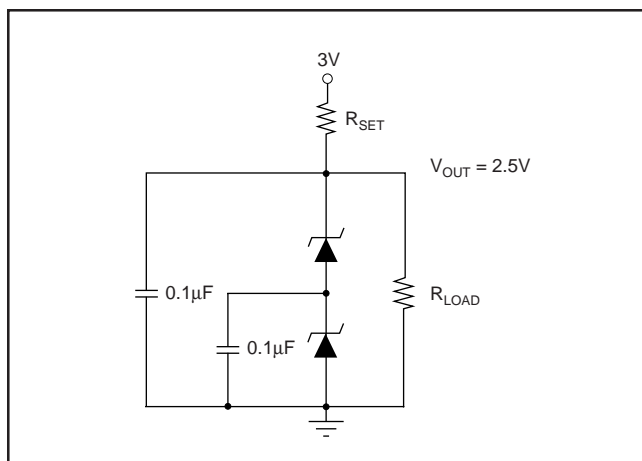


FIGURE 4. 2.5V Reference on 1µA.

For applications requiring a stable voltage reference capable of sinking higher than 5mA of current, a REF1112 combined with an OPA347 can sink up to 10mA of current. This configuration is shown in Figure 5, and through appropriate selection of R1 and R2, can be used to provide a wide range of stable reference voltages. The REF1112 is also useful for level shifting, and as shown in Figure 6, can be used to achieve the full input range of an analog-to-digital converter (ADC).

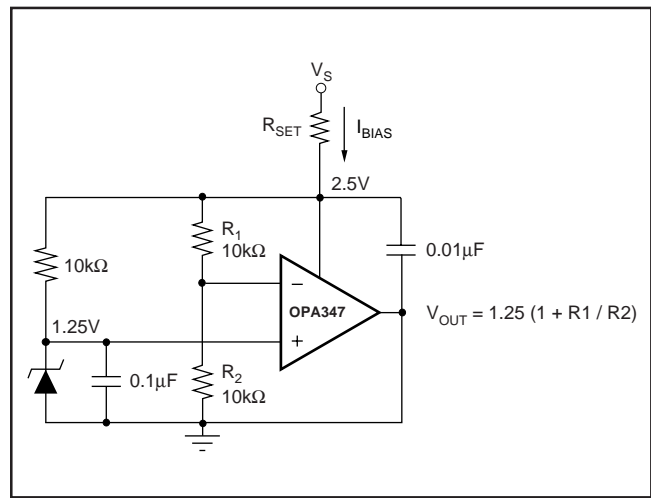


FIGURE 5. Adjustable Voltage Shunt Reference.

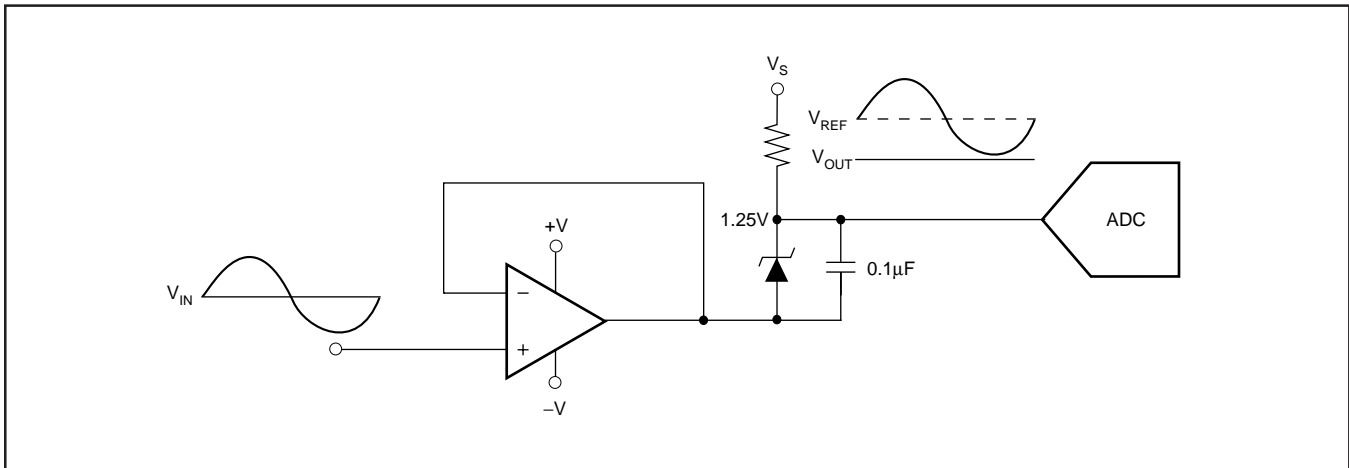


FIGURE 6. REF1112 Provides a Level Shift to Achieve Full ADC Input Range.

**PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)	Op Temp (°C)	Top-Side Markings (4)	Samples
REF1112AIDBZR	ACTIVE	SOT-23	DBZ	3	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	R11A	<a href="#">Samples</a>
REF1112AIDBZRG4	ACTIVE	SOT-23	DBZ	3	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	R11A	<a href="#">Samples</a>
REF1112AIDBZT	ACTIVE	SOT-23	DBZ	3	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	R11A	<a href="#">Samples</a>
REF1112AIDBZTG4	ACTIVE	SOT-23	DBZ	3	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	R11A	<a href="#">Samples</a>

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

**Green (RoHS & no Sb/Br):** TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) Multiple Top-Side Markings will be inside parentheses. Only one Top-Side Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Top-Side Marking for that device.

**Important Information and Disclaimer:** The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.





## TAPE AND REEL INFORMATION



### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
REF1112AIDBZR	SOT-23	DBZ	3	3000	179.0	8.4	3.15	2.95	1.22	4.0	8.0	Q3
REF1112AIDBZT	SOT-23	DBZ	3	250	179.0	8.4	3.15	2.95	1.22	4.0	8.0	Q3

**TAPE AND REEL BOX DIMENSIONS**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
REF1112AIDBZR	SOT-23	DBZ	3	3000	203.0	203.0	35.0
REF1112AIDBZT	SOT-23	DBZ	3	250	203.0	203.0	35.0

## GENERIC PACKAGE VIEW

**DBZ 3**

**SOT-23 - 1.12 mm max height**

SMALL OUTLINE TRANSISTOR



Images above are just a representation of the package family, actual package may vary.  
Refer to the product data sheet for package details.

4203227/C

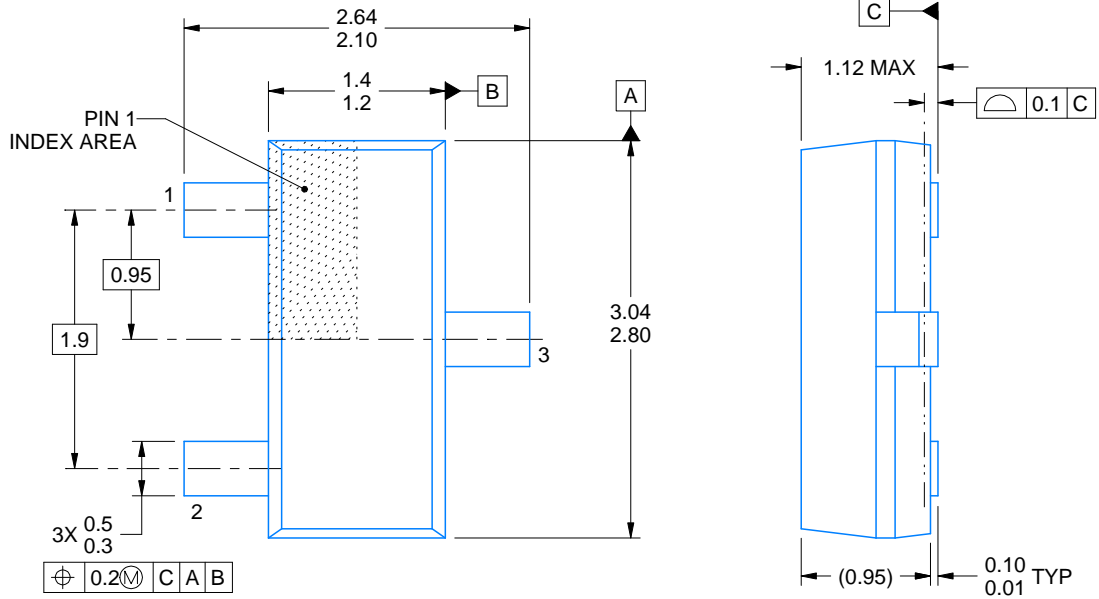
DBZ0003A



# PACKAGE OUTLINE

## SOT-23 - 1.12 mm max height

SMALL OUTLINE TRANSISTOR



4214838/C 04/2017

### NOTES:

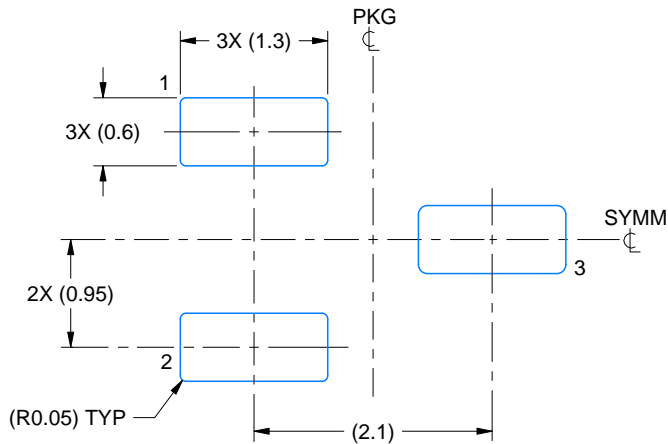
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Reference JEDEC registration TO-236, except minimum foot length.

# EXAMPLE BOARD LAYOUT

DBZ0003A

SOT-23 - 1.12 mm max height

SMALL OUTLINE TRANSISTOR



LAND PATTERN EXAMPLE  
SCALE:15X



SOLDER MASK DETAILS

4214838/C 04/2017

NOTES: (continued)

4. Publication IPC-7351 may have alternate designs.
5. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

# EXAMPLE STENCIL DESIGN

DBZ0003A

SOT-23 - 1.12 mm max height

SMALL OUTLINE TRANSISTOR



SOLDER PASTE EXAMPLE  
BASED ON 0.125 THICK STENCIL  
SCALE:15X

4214838/C 04/2017

NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
7. Board assembly site may have different recommendations for stencil design.

## IMPORTANT NOTICE

Texas Instruments Incorporated (TI) reserves the right to make corrections, enhancements, improvements and other changes to its semiconductor products and services per JESD46, latest issue, and to discontinue any product or service per JESD48, latest issue. Buyers should obtain the latest relevant information before placing orders and should verify that such information is current and complete.

TI's published terms of sale for semiconductor products (<http://www.ti.com/sc/docs/stdterms.htm>) apply to the sale of packaged integrated circuit products that TI has qualified and released to market. Additional terms may apply to the use or sale of other types of TI products and services.

Reproduction of significant portions of TI information in TI data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. TI is not responsible or liable for such reproduced documentation. Information of third parties may be subject to additional restrictions. Resale of TI products or services with statements different from or beyond the parameters stated by TI for that product or service voids all express and any implied warranties for the associated TI product or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Buyers and others who are developing systems that incorporate TI products (collectively, "Designers") understand and agree that Designers remain responsible for using their independent analysis, evaluation and judgment in designing their applications and that Designers have full and exclusive responsibility to assure the safety of Designers' applications and compliance of their applications (and of all TI products used in or for Designers' applications) with all applicable regulations, laws and other applicable requirements. Designer represents that, with respect to their applications, Designer has all the necessary expertise to create and implement safeguards that (1) anticipate dangerous consequences of failures, (2) monitor failures and their consequences, and (3) lessen the likelihood of failures that might cause harm and take appropriate actions. Designer agrees that prior to using or distributing any applications that include TI products, Designer will thoroughly test such applications and the functionality of such TI products as used in such applications.

TI's provision of technical, application or other design advice, quality characterization, reliability data or other services or information, including, but not limited to, reference designs and materials relating to evaluation modules, (collectively, "TI Resources") are intended to assist designers who are developing applications that incorporate TI products; by downloading, accessing or using TI Resources in any way, Designer (individually or, if Designer is acting on behalf of a company, Designer's company) agrees to use any particular TI Resource solely for this purpose and subject to the terms of this Notice.

TI's provision of TI Resources does not expand or otherwise alter TI's applicable published warranties or warranty disclaimers for TI products, and no additional obligations or liabilities arise from TI providing such TI Resources. TI reserves the right to make corrections, enhancements, improvements and other changes to its TI Resources. TI has not conducted any testing other than that specifically described in the published documentation for a particular TI Resource.

Designer is authorized to use, copy and modify any individual TI Resource only in connection with the development of applications that include the TI product(s) identified in such TI Resource. NO OTHER LICENSE, EXPRESS OR IMPLIED, BY ESTOPPEL OR OTHERWISE TO ANY OTHER TI INTELLECTUAL PROPERTY RIGHT, AND NO LICENSE TO ANY TECHNOLOGY OR INTELLECTUAL PROPERTY RIGHT OF TI OR ANY THIRD PARTY IS GRANTED HEREIN, including but not limited to any patent right, copyright, mask work right, or other intellectual property right relating to any combination, machine, or process in which TI products or services are used. Information regarding or referencing third-party products or services does not constitute a license to use such products or services, or a warranty or endorsement thereof. Use of TI Resources may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

TI RESOURCES ARE PROVIDED "AS IS" AND WITH ALL FAULTS. TI DISCLAIMS ALL OTHER WARRANTIES OR REPRESENTATIONS, EXPRESS OR IMPLIED, REGARDING RESOURCES OR USE THEREOF, INCLUDING BUT NOT LIMITED TO ACCURACY OR COMPLETENESS, TITLE, ANY EPIDEMIC FAILURE WARRANTY AND ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE, AND NON-INFRINGEMENT OF ANY THIRD PARTY INTELLECTUAL PROPERTY RIGHTS. TI SHALL NOT BE LIABLE FOR AND SHALL NOT DEFEND OR INDEMNIFY DESIGNER AGAINST ANY CLAIM, INCLUDING BUT NOT LIMITED TO ANY INFRINGEMENT CLAIM THAT RELATES TO OR IS BASED ON ANY COMBINATION OF PRODUCTS EVEN IF DESCRIBED IN TI RESOURCES OR OTHERWISE. IN NO EVENT SHALL TI BE LIABLE FOR ANY ACTUAL, DIRECT, SPECIAL, COLLATERAL, INDIRECT, PUNITIVE, INCIDENTAL, CONSEQUENTIAL OR EXEMPLARY DAMAGES IN CONNECTION WITH OR ARISING OUT OF TI RESOURCES OR USE THEREOF, AND REGARDLESS OF WHETHER TI HAS BEEN ADVISED OF THE POSSIBILITY OF SUCH DAMAGES.

Unless TI has explicitly designated an individual product as meeting the requirements of a particular industry standard (e.g., ISO/TS 16949 and ISO 26262), TI is not responsible for any failure to meet such industry standard requirements.

Where TI specifically promotes products as facilitating functional safety or as compliant with industry functional safety standards, such products are intended to help enable customers to design and create their own applications that meet applicable functional safety standards and requirements. Using products in an application does not by itself establish any safety features in the application. Designers must ensure compliance with safety-related requirements and standards applicable to their applications. Designer may not use any TI products in life-critical medical equipment unless authorized officers of the parties have executed a special contract specifically governing such use. Life-critical medical equipment is medical equipment where failure of such equipment would cause serious bodily injury or death (e.g., life support, pacemakers, defibrillators, heart pumps, neurostimulators, and implantables). Such equipment includes, without limitation, all medical devices identified by the U.S. Food and Drug Administration as Class III devices and equivalent classifications outside the U.S.

TI may expressly designate certain products as completing a particular qualification (e.g., Q100, Military Grade, or Enhanced Product). Designers agree that it has the necessary expertise to select the product with the appropriate qualification designation for their applications and that proper product selection is at Designers' own risk. Designers are solely responsible for compliance with all legal and regulatory requirements in connection with such selection.

Designer will fully indemnify TI and its representatives against any damages, costs, losses, and/or liabilities arising out of Designer's non-compliance with the terms and provisions of this Notice.